## Spintronic operation in antiferromagnets

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#### <u>Highlights</u>

- 1. Spin pumping in FM/AFM
- 2. Terahertz spin pumping in AFM
- 3. Fabrication of chiral antiferromagnet  $Mn_3Ir$



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## Possibility of antiferromagnetic spintronics

		Magnetic susceptibility	Resonant frequency		
	FM	~ 10 <sup>3</sup> *	A few 10 GHz		
	AFM	~ 10 <sup>-2</sup> **	A few THz	* Typical value of Fe ** Typical value of MnF <sub>2</sub>	
				2	
Small susceptibility		usceptibility	THz dynamics		
Ultra high density memory Tolerance to field disturbance			High speed magnetization switching THz emission		
Close packed memory bits			THz	emission	
Bit: 0	Bit: 0		Spin current	THz	
FM memory Bit interference due to stray field	FM memoryNo stray field allows 100Sit interferencetimes more packed bits*ue to stray field*S. Loth et al., Science 335, 196 (2012).		THz emission u resonance ex	THz emission using antiferromagnetic resonance excited by spin current	

See reviews in: Jungwirth et al., Nat. Nanotechnol., 11, 231 (2016), and Baltz, TM, et al., RPM 90, 015005 (2018)

# Spin current interaction in AFM

How is the spin torque exerting in antiferromagnets?



## Spin current dissipation and spin torque



### Damping enhancement by spin pumping effect

#### Damping enhancement as a probe of spin torque effect.



FM/NM spin pumping

Damping  $\alpha$  of the FM (FMR linewidth) is enhanced due to the spin current dissipation in NM.

$$\alpha \propto \mathbf{I}_{s}^{pump} - \mathbf{I}_{s}^{(0)} \qquad \begin{cases} \mathbf{I}_{s}^{pump} = \frac{g_{r}^{\uparrow\downarrow}}{4\pi} \mathbf{m} \times \frac{\mathrm{d}\mathbf{m}}{\mathrm{d}t} \\ \mathbf{I}_{s}^{(0)} = \frac{g_{r}^{\uparrow\downarrow}}{4\pi} \mathbf{m} \times \boldsymbol{\mu}_{s} \times \mathbf{m} \end{cases}$$

Tserkovnyak, et al. RMP 77, 1375 (2005)

Mizukami, PRB 66, 104413 (2002)



Damping enhancement  $\propto \left[1 + \tilde{g}_r^{\uparrow\downarrow} R_{sd} \frac{1 + \tanh(t_{Cu}/\lambda_{Cu})\tilde{g}R_{sd}}{\tanh(t_{Cu}/\lambda_{Cu}) + \tilde{g}R_{sd}}\right]^{-1}$ 



# Damping enhancement with AFM

Damping enhancement as a probe of spin dissipation in AFM.



# Damping vs. FeMn thickness



Spin current carried by spin fluctuation; PRL **113**, 097202 (2014).; APL **106**, 162406 (2015); PRB **92**, 020409R (2015).; PRL **118**, 147202 (2017).

## Damping enhancement vs. AFM magnetic structure



## AFM twisting and damping enhancement



Damping is maximized at the relative angle  $\sim 180^{\circ}$  at which the twisting is maximized.

Moriyama, *PRL* 119, 267204 (2017)

# Damping control by temperature



Damping drastically changes in the temperature range of 300 ~ 400 K.

 $\rightarrow$  Beneficial for spintronic devices where Joule heating is involved during the operation (*e.g.* STT-MRAM)

## Antiferromagnetic resonance



# Chiral antiferromagnets: Mn<sub>3</sub>X



Ajaya K. Nayak, et al., Sci. Adv. 2, e1501870 (2016).



	$\frac{AHC}{\sigma}$
symmetry-imposed tensor shape	$\begin{pmatrix} 0 & \sigma_{xy} & 0 \\ -\sigma_{xy} & 0 & 0 \\ 0 & 0 & 0 \end{pmatrix}$
Mn <sub>3</sub> Rh	$\begin{pmatrix} 0 & -284 & 0 \\ 284 & 0 & 0 \\ 0 & 0 & 0 \end{pmatrix}$
Mn <sub>3</sub> Ir	$\begin{pmatrix} 0 & -312 & 0 \\ 312 & 0 & 0 \\ 0 & 0 & 0 \end{pmatrix}$
Mn <sub>3</sub> Pt	$\begin{pmatrix} 0 & 98 & 0 \\ -98 & 0 & 0 \\ 0 & 0 & 0 \end{pmatrix}$

Zhang, PRB 95, 075128 (2017)

Measurements on Mn<sub>3</sub>Ir?

# Summary

### 1. Spin pumping in AFM/FM bilayer:

ightarrow Control spin dissipation by the AFM order

#### ightarrow FM damping is controlled by AFM

APL **106**, 162406 (2015); PRB **92**, 020409R(2015); PRL **119**, 267204 (2017); APEX **11**, 073003 (2018); PRApplied **11**, 011001 (2019)

### 2. Antiferromagnetic spin pumping:

 $\rightarrow$  Experimentally observed for the first time.

→ Large  $g_{\uparrow\downarrow}$  = 43 nm<sup>-2</sup> was determined.

*PRMatererials* **3**, 051402 (2019); manuscript under review

## 3. AHE in Mn<sub>3</sub>Ir:

 $\rightarrow$  Positive correlation between S and AH conductivity

 $\rightarrow$  AH conductivity is ~40  $\Omega^{-1}$  cm<sup>-1</sup>



**High damping** 





# Collaborations & Acknowledgements



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Thank you for your attention!